

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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MOS FIELD EFFECT TRANSISTOR

2SK2480

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK2480 is N-Channel MOS Field Effect Transistor designed for high voltage switching applications.

FEATURES

- Low On-Resistance
 $R_{DS(on)} = 4.0\ \Omega$ ($V_{GS} = 10\ V$, $I_D = 2.0\ A$)
- Low C_{iss} $C_{iss} = 900\ pF$ TYP.
- High Avalanche Capability Ratings
- Isolated TO-220 Package

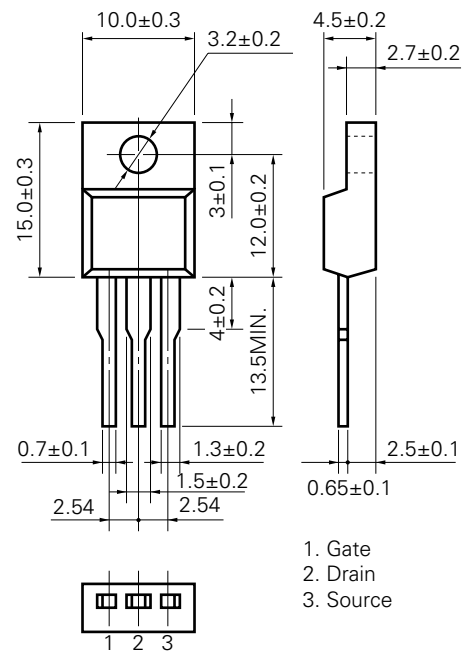
ABSOLUTE MAXIMUM RATINGS ($T_A = 25\ ^\circ C$)

Drain to Source Voltage	V_{BSS}	900	V
Gate to Source Voltage	V_{GSS}	± 30	V
Drain Current (DC)	$I_{D(DC)}$	± 3.0	A
Drain Current (pulse)*	$I_{D(pulse)}$	± 12	A
Total Power Dissipation ($T_c = 25\ ^\circ C$)	P_{T1}	35	W
Total Power Dissipation ($T_A = 25\ ^\circ C$)	P_{T2}	2.0	W
Channel Temperature	T_{ch}	150	$^\circ C$
Storage Temperature	T_{stg}	-55 to $+150$	$^\circ C$
Single Avalanche Current**	I_{AS}	3.0	A
Single Avalanche Energy**	E_{AS}	37.1	mJ

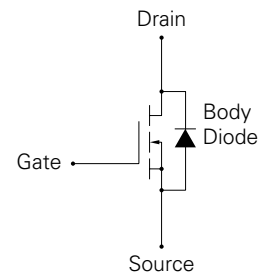
* $PW \leq 10\ \mu s$, Duty Cycle $\leq 1\ \%$

** Starting $T_{ch} = 25\ ^\circ C$, $R_G = 25\ \Omega$, $V_{GS} = 20\ V \rightarrow 0$

PACKAGE DIMENSIONS (in millimeter)



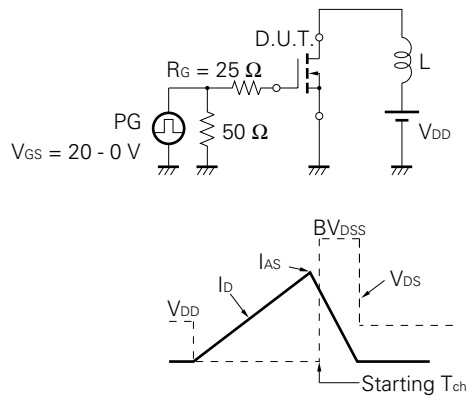
MP-45F (ISOLATED TO-220)



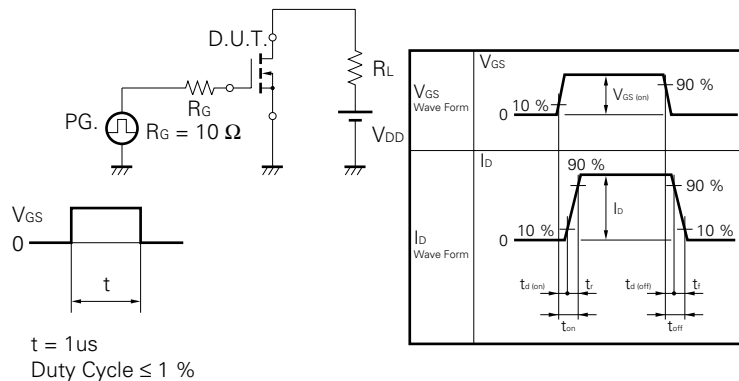
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	R _{DS(on)}		3.2	4.0	Ω	V _{GS} = 10 V, I _D = 2.0 A
Gate to Source Cutoff Voltage	V _{GS(off)}	2.5		3.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	y _{fs}	1.0			S	V _{DS} = 20 V, I _D = 2.0 A
Drain Leakage Current	I _{DSS}			100	μA	V _{DS} = V _{DSS} , V _{GS} = 0
Gate to Source Leakage Current	I _{GSS}			±100	nA	V _{GS} = ±30 V, V _{DS} = 0
Input Capacitance	C _{iss}		900		pF	V _{DS} = 10 V V _{GS} = 0 f = 1 MHz
Output Capacitance	C _{oss}		130		pF	
Reverse Transfer Capacitance	C _{rss}		25		pF	
Turn-On Delay Time	t _{d(on)}		17		ns	I _D = 2.0 A V _{GS} = 10 V V _{DD} = 150 V R _G = 75 Ω
Rise Time	t _r		7		ns	
Turn-Off Delay Time	t _{d(off)}		63		ns	
Fall Time	t _f		8		ns	
Total Gate Charge	Q _G		30		nC	I _D = 3.0 A V _{DD} = 450 V V _{GS} = 10 V
Gate to Source Charge	Q _{GS}		5		nC	
Gate to Drain Charge	Q _{GD}		16		nC	
Body Diode Forward Voltage	V _{F(S-D)}		1.0		V	I _F = 3.0 A, V _{GS} = 0
Reverse Recovery Time	t _{rr}		650		ns	I _F = 3.0 A, V _{GS} = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Q _{rr}		2.8		μC	

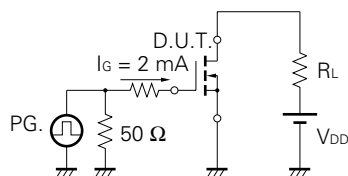
Test Circuit 1 Avalanche Capability



Test Circuit 2 Switching Time

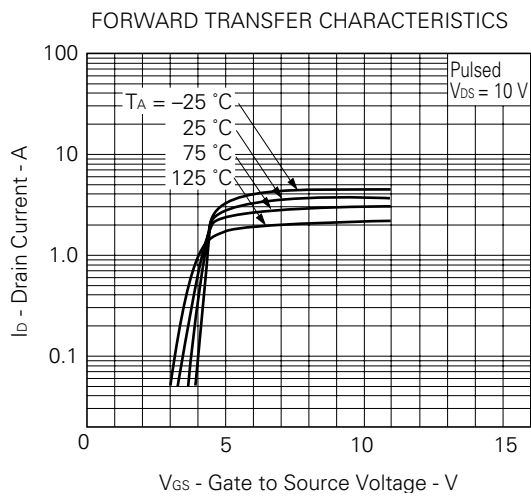
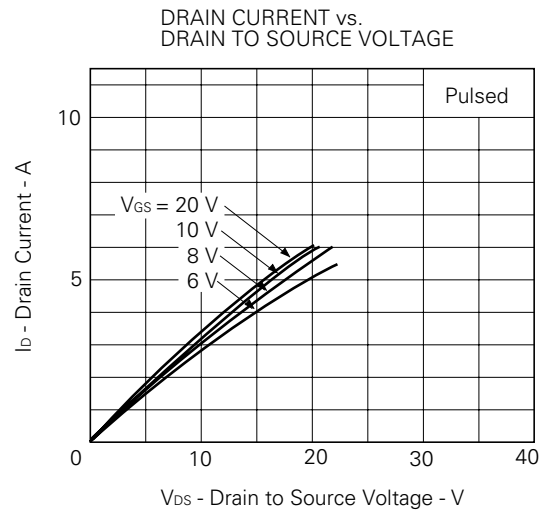
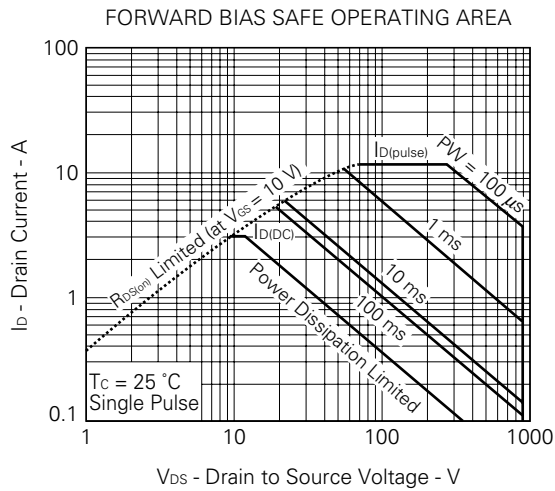
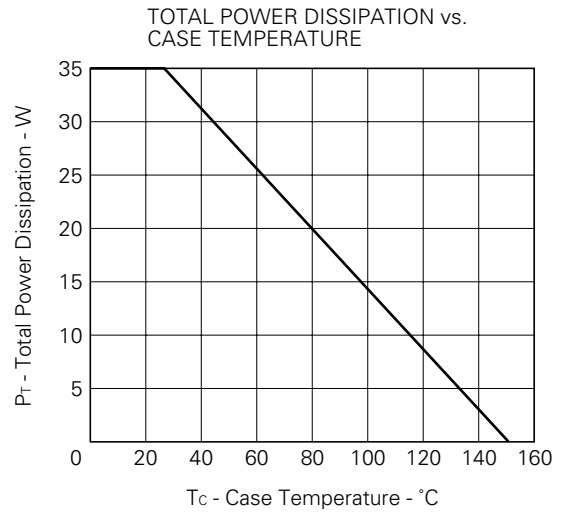
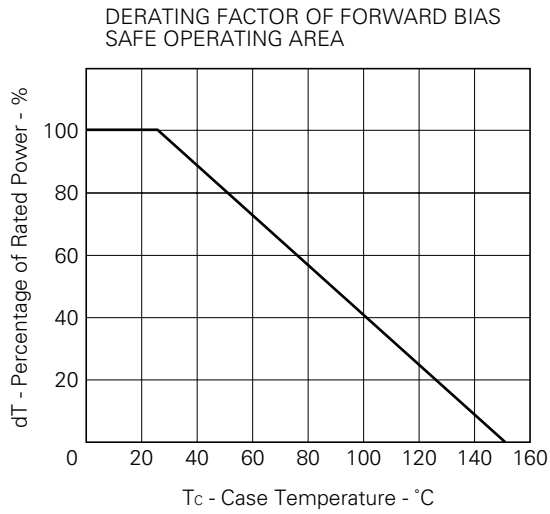


Test Circuit 3 Gate Charge

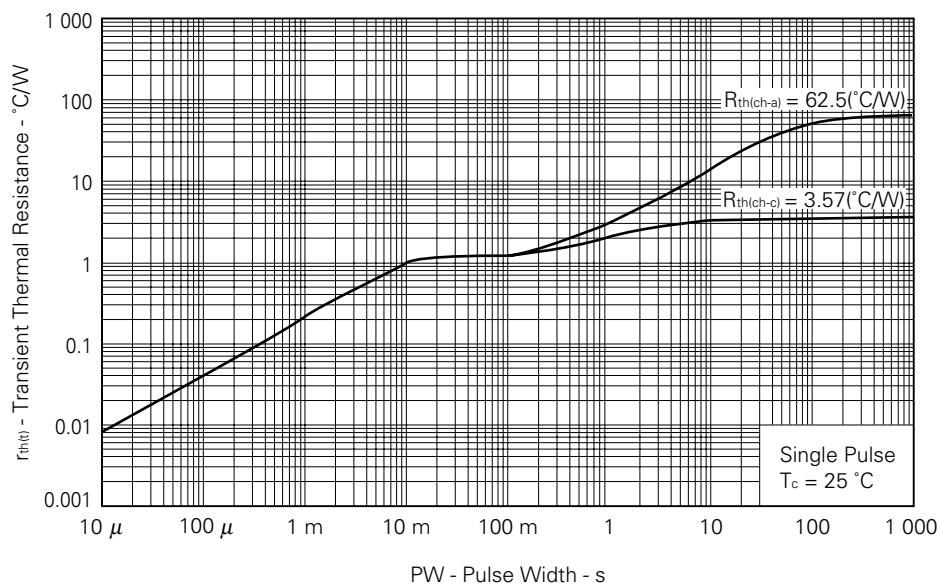


The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

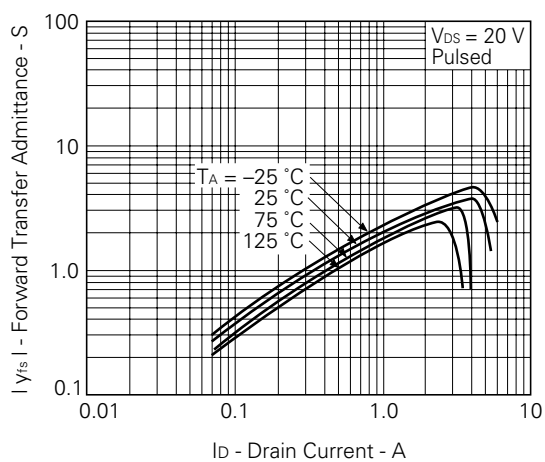
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



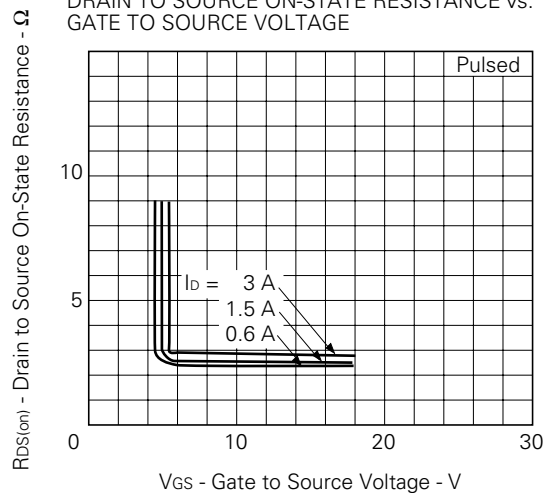
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



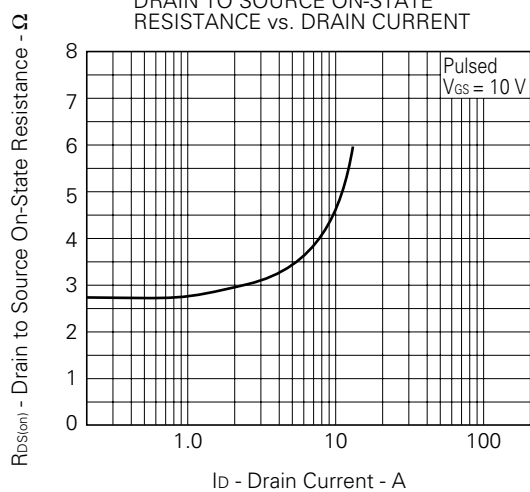
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



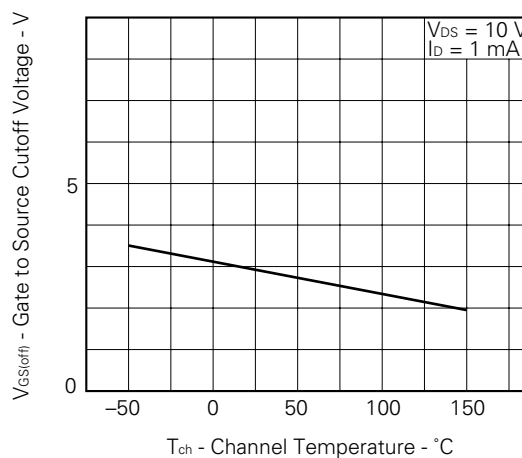
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

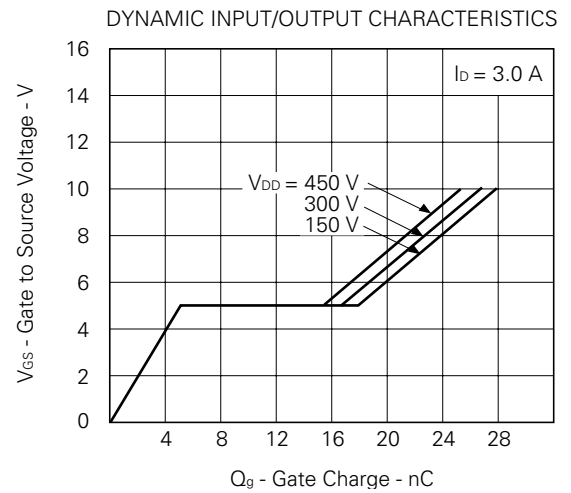
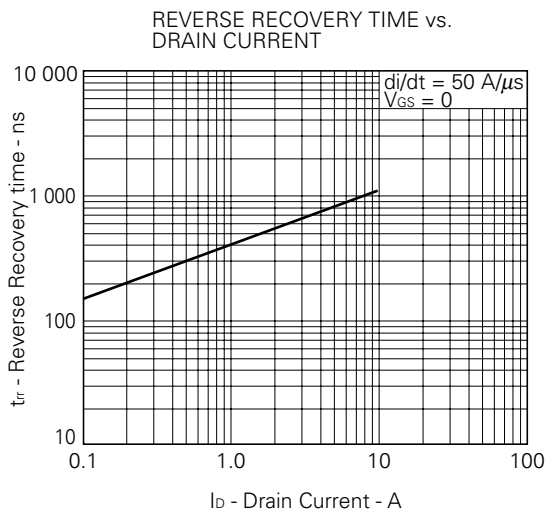
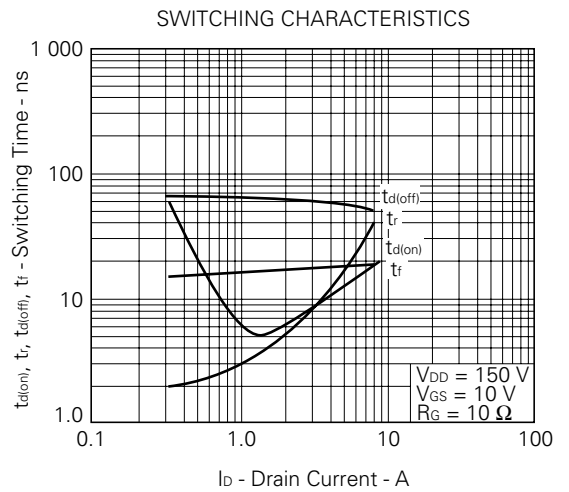
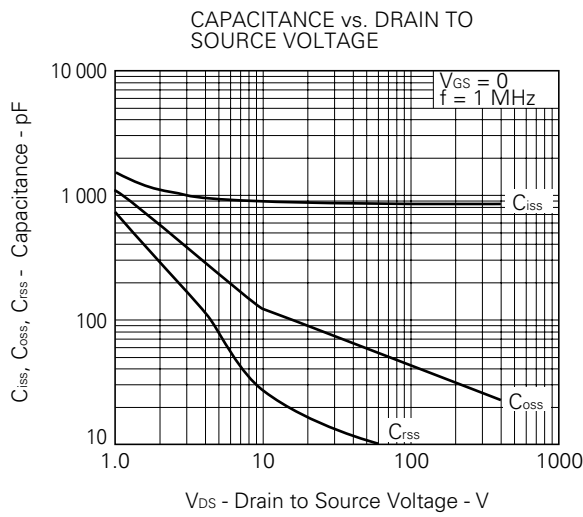
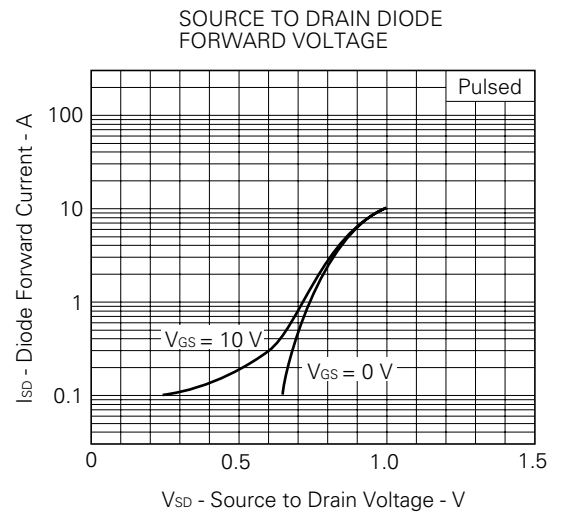
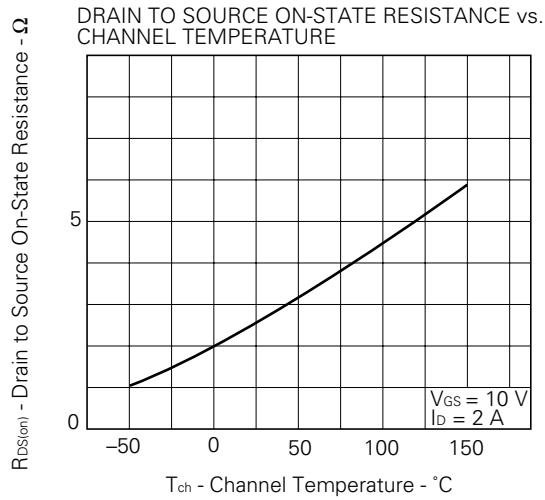


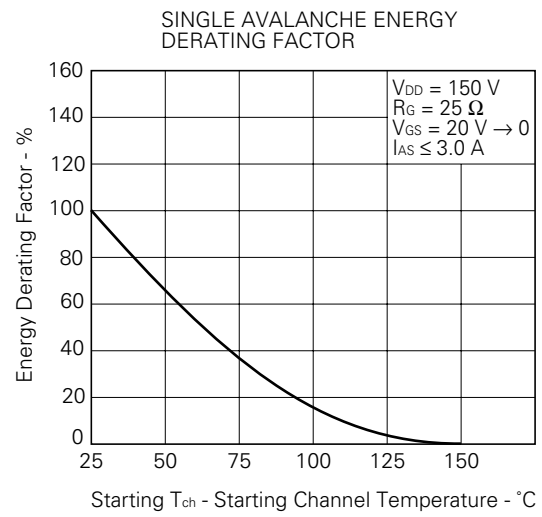
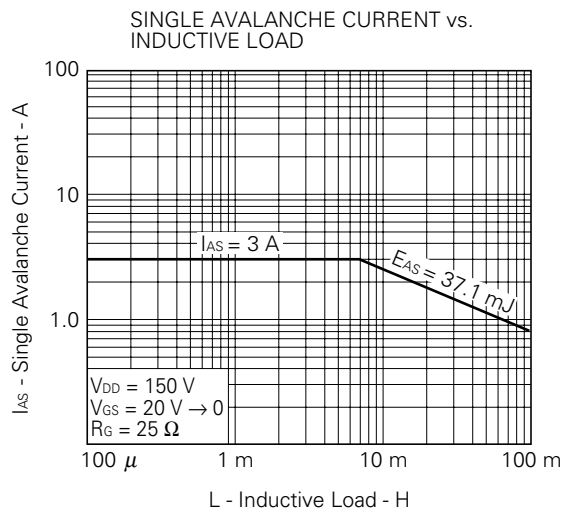
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE







REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

[MEMO]

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